

Supporting information

Interfacial Properties of Anisotropic Monolayer SiAs Transistors

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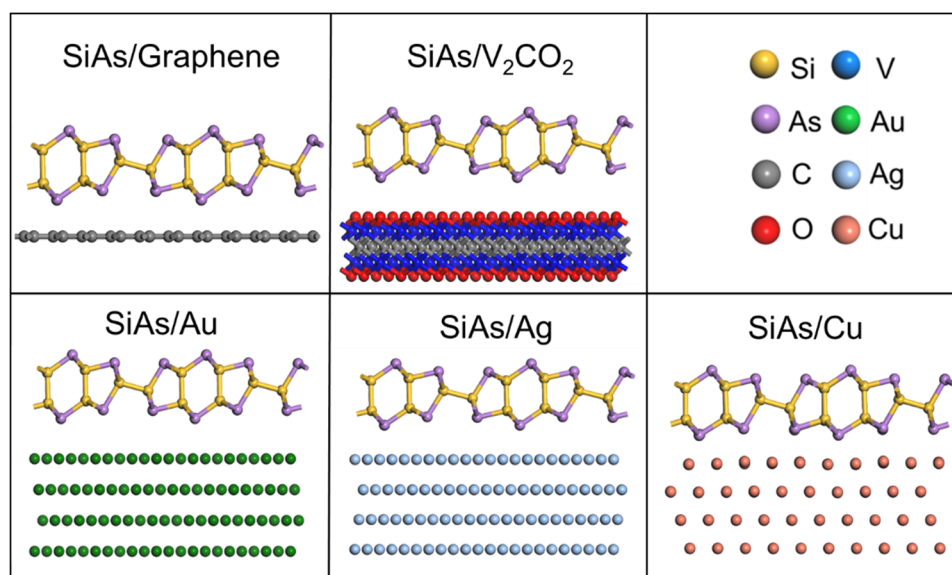


Figure S1. Side views of the non-optimized structures of ML SiAs on graphene, V₂CO₂, Au, Ag, and Cu surfaces.